

BD681G

BD681G Information



For Reference Only

Part Number	BD681G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 100V 4A TO225AA
Package	TO-225AA, TO-126-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



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Certified Quality

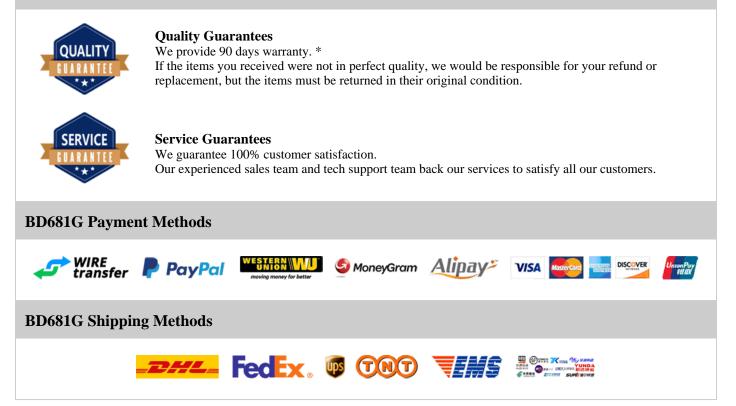
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BD681G Specifications

Manufacturer Part Number	BD681G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-225AA, TO-126-3
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	4A
Voltage - Collector Emitter Breakdown (Max)	100V
Vce Saturation (Max) @ Ib, Ic	2.5V @ 30mA, 1.5A
Current - Collector Cutoff (Max)	500µA
DC Current Gain (hFE) (Min) @ Ic, Vce	750 @ 1.5A, 3V
Power - Max	40W
Frequency - Transition	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-225AA, TO-126-3
Supplier Device Package	TO-225AA
	Report errors?

BD681G Guarantees



If you have any question about BD681G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com